



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Yasuhiko NOMURA et al.**

Serial No.: 09/666,553 ✓

Group Art Unit: 2828

Filed: September 21, 2000

Examiner: **Quyen Phan Leung**

P.T.O. Confirmation No.: 7592

For: **SEMICONDUCTOR LIGHT EMITTING DEVICE**

RESPONSE UNDER 37 C.F.R. §1.116
- EXPEDITED RESPONSE -
GROUP ART UNIT 2828

BOX AF

Commissioner for Patents
Washington, D.C. 20231

April 7, 2003

Sir:

In response to the Office Action dated November 5, 2002, the response due date extended to April 5, 2003 by a concurrently filed two-month Extension of Time, Applicants amend the above-identified application as follows:

IN THE CLAIMS:

Please amend claims 1, 8, 11 and 17 as follows:

1. (Amended) A semiconductor light emitting device comprising:
 - a nitride-based semiconductor layer including an emission layer; and
 - a dielectric film formed on the surface of said nitride-based semiconductor layer, wherein said dielectric film contains a nitride formed directly on the surface of said nitride-based semiconductor layer while containing an oxide formed on said nitride.

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